Specification

(1200A/3300V-1in1 IGBT-Module)

Device Name : IGBT-Module

Type Name : 1MBI1200UE-330

Spec. No. : MS5F07547

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	DATE	NAME	APPROVAL	E	i Electric Syste	ms Co. I td
DRAWN	31-May-'10	T.Koga		Fuj	i Electric Syste	ilis Co.,Liu.
CHECKED	02-Jun-'10	H.Kakiki	O.Ikawa	J.No.	MS5E07547	1 / 14
CHECKED	04-Jun-'10	K.Ohshika		DWC	MS5F07547	1 / 14

Revised Records

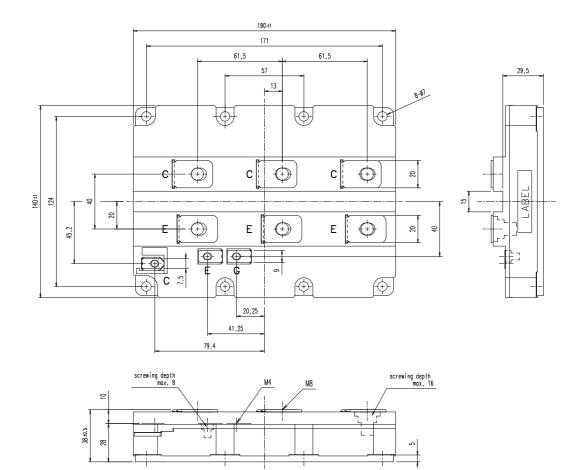
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Date	Classifi - cation	Ind.	Content	Applied date	Drawn	Checked	Checked	Approved
02-Jun-'10	enactment	1	-	Issued data	-	H.Kakiki	K.Ohshika	O.Ikawa
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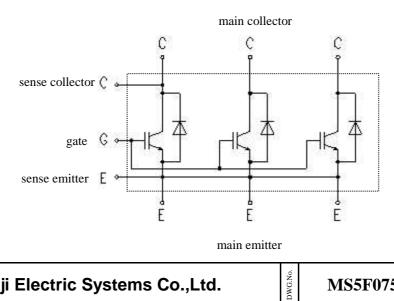
Type Name: 1MBI1200UE-330 / PKG.No. M152

1. Outline Drawing (Unit : mm)



2. Equivalent circuit

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3.Absolute Maximum Ratings (at Tc= $25\,^{\circ}\text{C}$ unless otherwise specified)

Items		Symbols	Cond	itions	Maximum Ratings	Units
Collector-E	Emitter voltage	VCES			3300	V
Gate-Emitt	er voltage	VGES			±20	V
		Ic	Continuous	Tc=25°C	2000	
		ic	Continuous	Tc=80°C	1200	
Callagton	numont.	Lon	1ms	Tc=25°C	4000	A
Collector current		Icp	11118	Tc=80°C	2400	A
					1200	
			1ms		2400	1
Collector P	ower Dissipation	Pc	1 device		14.7	kW
Junction te	mperature	Tj			150	°C
Storage ten	nperature	Tstg			-40 ~ +125	
Isolation voltage	between terminal and copper base *1	Viso	AC: 1min.		6.0	kVAC
Partial discharge extinction voltage		Ve	AC, Q 10pC (acc. To IEC 1287)		2.6	kVAC
Screw Torque *2		Mounting			5.75	Nm
		Main Terminals	S		10	IN III
		Sense Terminals			2.5	1

^(*1) All terminals should be connected together when isolation test will be done.

(*2) Recommendable Value : Mounting 4.25~5.75 Nm (M6) Main Terminals 8~10 Nm (M8) Sense Terminals 1.7~2.5 Nm (M4)

4. Electrical characteristics (at Tj= 25°C unless otherwise specified)

T40ma	Count ole	Condit		Cl	haracterist	tics	Units	
Items	Symbols	Conditions		min.	typ.	max.	Units	
Zero gate voltage Collector current	ICES	VGE = 0V $VCE = 3300V$		-	-	1.0	mA	
Gate-Emitter leakage current	IGES	VCE = 0V VGE=±20V		-	-	4800	nA	
Gate-Emitter threshold voltage	VGE(th)	VCE = 20V Ic = 1200mA		6.0	6.75	7.5	V	
	VCE(sat)	VGE=15V	Tj= 25°C	-	2.43	2.66		
Collector-Emitter	(main terminal)	VGE=13V	Tj=125°C	-	3.15	3.45	V	
saturation voltage	VCE(sat)	Ic = 1200A	Tj=25°C	-	2.28	2.51		
	(chip)	IC = 1200A	Tj=125°C	-	3.00	3.30		
Input capacitance	Cies	VCE=10V,VGE=	0V,f=1MHz	-	240	-	nF	
	ton	Vcc = 1800V		-	3.40	-		
Turn-on	tr	Ic = 1200A VGE=±15V,Tj=12	25	-	2.30	-	μs	
Turn-off	toff	$Rg = 1.6 \Omega$		-	2.40	-		
I um-on	tf	1		-	0.40	-	1	
	VF	VGE=0V	Tj=25°C	-	2.73	2.96		
Forward on voltage	(main terminal)	VGE=UV	Tj=125°C	-	2.95	3.25	v	
Forward on voltage	VF	IF = 1200A	Tj= 25°C	-	2.58	2.81		
	(chip)	H - 1200A	Tj=125°C	-	2.80	3.10		
Reverse recovery	trr	IF = 1200A		-	0.85	-	μs	
Lead resistance, terminal-chip	R lead			-	0.124	-	mΩ	

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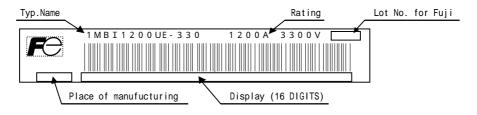
DWG.No.

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Items	Symbols	Conditions	Cl	Units		
Items	Symbols	Conditions	min.	typ.	max.	Units
Thermal resistance(1device)	Dth(i, a)	IGBT	-	-	8.5	
Thermal resistance (Tuevice)	Rth(j-c)	FWD	-	-	17.0	°C/kW
Contact Thermal resistance(1device)	Rth(c-f)	with Thermal Compound (*)	-	4.0	-	

^{*} This is the value which is defined mounting on the additional cooling fin with thermal compound.

6. Indication on module



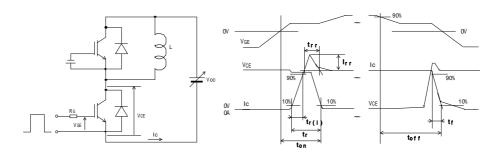
7. Applicable category

This specification is applied to IGBT Module named 1MBI1200UE-330.

8. Storage and transportation notes

- The module should be stored at a standard temperature of 5 to 35° C and humidity of 45 to 75%.
- Store modules in a place with few temperature changes in order to avoid condensation on the module surface.
- Avoid exposure to corrosive gases and dust.
- Avoid excessive external force on the module.
- Store modules with unprocessed terminals.
- Do not drop or otherwise shock the modules when transporting.

9. Definitions of switching time



10. Packing and Labeling

Display on the packing box

- Logo of production
- Type name
- Lot No
- Products quantity in a packing box

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11.Reliability test results

Reliability Test Items

Test cate- gories		Test items	Test met	thods and conditions	Reference norms EIAJ ED-4701 (Aug2001 edition)	Number of sample	Accept- ance number
		Terminal Strength	Pull force	: 40N	Test Method 401	5	(0:1)
		(Pull test)		: 10±1 sec.	Method		
	2	Mounting Strength	Screw torque	: 1.7 ~ 2.5 N·m (M4)	Test Method 402	5	(0:1)
S				4.25 ~ 5.75 N·m (M6)	Method		
est				8.0~ 10.0 N·m (M8)			
Mechanical Tests				: 10±1 sec.		_	
, je	3	Vibration	Range of frequency: 10		Test Method 403	5	(0:1)
þar				: 15 min.	Reference 1		
Jec				: 100m/s ²	Condition code B		
2			Sweeping direction : Each				
				: 6 hr. (2hr./direction)			
	4	Shock	Maximum acceleration		Test Method 404	5	(0:1)
				: 6.0msec.	Condition code A		
				: Each X,Y,Z axis			
				: 3 times/direction			
		High Temperature		: 125±5	Test Method 201	5	(0:1)
	_	Storage		: 1000hr.		_	
		Low Temperature	Storage temp.	: -40±5	Test Method 202	5	(0:1)
	_	Storage		: 1000hr.		_	
		Temperature		: 85±2	Test Method 103	5	(0:1)
		Humidity	1	: 85±5%	Test code C		
	_	Storage		: 1000hr.			
		Unsaturated	1 '	: 120 ± 2	Test Method 103	5	(0:1)
		Pressurized Vapor	1 '	: 85±5%	Test code E		
			Test duration	: 96hr.			
Environment Tests		Temperature Cycle	Test temp.	: Low temp40 ± 5	Test Method 105	5	(0:1)
onmen				—High temp. 125 ±5			
Nir				└─ RT 5 ~ 35			
ū			Dwell time	: High ~ RT ~ Low ~ RT			
				1hr. 0.5hr. 1hr. 0.5hr.			
			Number of cycles	: 100 cycles			
	6	Thermal Shock		+0	Test Method 307	5	(0:1)
			Test temp.	: High temp. 100 ⁻⁵	Method		
				+5	Condition code A		
				Low temp. 0 ⁻⁰			
			Used liquid: Water with	·			
			· ·	: 5 min. par each temp.			
			1	: 10 sec.			
				: 10 cycles			
			•	•		-	

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Reliability Test Items

Test cate- gories		Test items	-	Test methods and conditions	Reference norms EIAJ ED-4701 (Aug2001 edition)	Number of sample	Accept- ance number
	1	High temperature			Test Method 101	5	(0:1)
		Reverse Bias	Test temp.	: Ta = 125 ± 5 (Tj 150)			
			Bias Voltage	: VC = 0.8×VCES			
			Bias Method	: Applied DC voltage to C-E			
				VGE = 0V			
			Test duration	: 1000hr.			
	2	High temperature			Test Method 101	5	(0:1)
		Bias (for gate)	Test temp.	: Ta = 125 ± 5			
				(Tj 150)			
sts			Bias Voltage	: $VC = VGE = +20V \text{ or } -20V$			
Te			Bias Method	: Applied DC voltage to G-E			
)ce				VCE = 0V			
Endurance Tests			Test duration	: 1000hr.			
ndt	3	Temperature			Test Method 102	5	(0:1)
ш		Humidity Bias	Test temp.	: 85 ± 2 °C	Condition code C		
			Relative humidity	∶ 85 ± 5%			
			Bias Voltage	: $VC = 0.8 \times VCES$			
			Bias Method	: Applied DC voltage to C-E			
				VGE = 0V			
			Test duration	: 1000hr.			
	4	Intermitted	ON time	: 2 sec.	Test Method 106	5	(0:1)
		Operating Life	OFF time	: 18 sec.			
		(Power cycle)	Test temp.	: ∆ Tj=100±5 deg			
		(for IGBT)	Ni salasa da s	Tj 150 , Ta=25±5			
			Number of cycles	: 15000 cycles			

Failure Criteria

Item	Characteristic		Symbol	Failure	criteria	Unit	Note
				Lower limit	Upper limit		
Electrical	Leakage curre	ent	ICES	-	USL×10	mA	
characteristic			±IGES	-	USL×2	μΑ	
	Gate threshole	Gate threshold voltage		LSL×0.8	USL×1.2	mΑ	
	Saturation voltage		VCE(sat)	-	USL×1.2	>	
	Forward voltage		VF		USL×1.2	>	
	Thermal	IGBT	∆ VGE	-	USL×1.2	mV	
	resistance		or ∆ VCE				
		FWD	ΔVF	-	USL×1.2	mV	
	Isolation voltage		Viso	Broken i	nsulation	•	
Visual	Visual inspection						
inspection	Peeling	[Peeling		The visua	al sample	-	
	Plating						
	and the oth	ners					

LSL: Lower specified limit. USL: Upper specified limit.

Note: Each parameter measurement read-outs shall be made after stabilizing the components at room ambient for 2 hours minimum, 24 hours maximum after removal from the tests. And in case of the wetting tests, for example, moisture resistance tests, each component shall be made wipe or dry completely before the measurement.

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Reliability Test Items

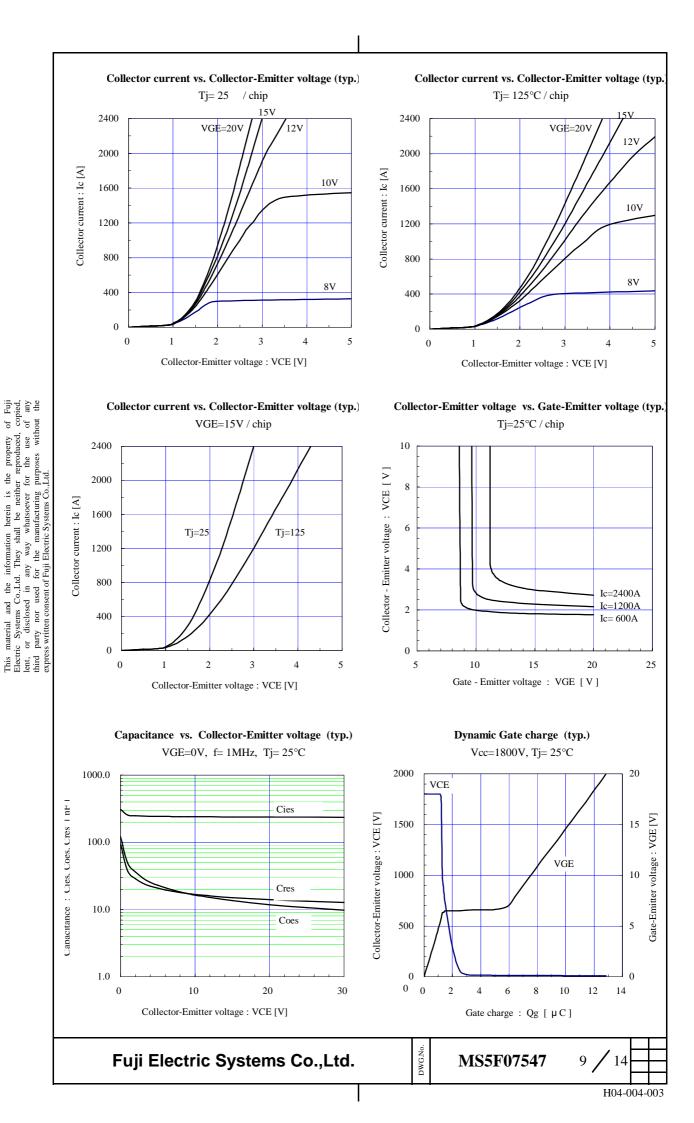
Test cate- gories		Test items	Reference norms EIAJ ED-4701 (Aug2001 edition)	Number of test sample	Number of failure sample
ts	Terminal Strength (Pull test)		Test Method 401 Method	5	0
cal Tes	2	Mounting Strength	Test Method 402 Method	5	0
Mechanical Tests	3	Vibration	Test Method 403 Condition code B	5	0
Ž	4	Shock	Test Method 404 Condition code B	5	0
	1	High Temperature Storage	Test Method 201	5	0
	2	Low Temperature Storage	Test Method 202	5	0
nt Tests	3	Temperature Humidity Storage	Test Method 103 Test code C	5	0
Environment Tests	4	Unsaturated Pressurized Vapor	Test Method 103 Test code E	5	0
Envi	5	Temperature Cycle	Test Method 105	5	0
	6	Thermal Shock	Test Method 307 method Condition code A	5	0
	1	High temperature Reverse Bias	Test Method 101	5	0
) Tests	2	High temperature Bias (for gate)	Test Method 101	5	0
Endurance Tests	3	Temperature Humidity Bias	Test Method 102 Condition code C	5	0
Enc	4	Intermitted Operating Life (Power cycling) (for IGBT)	Test Method 106	5	0

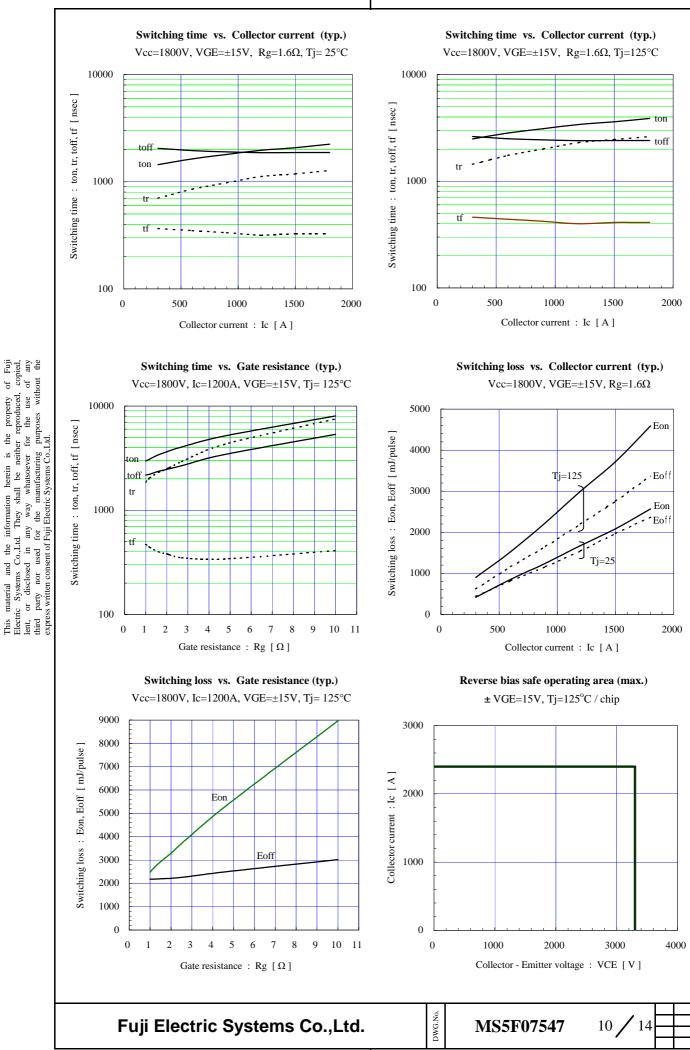
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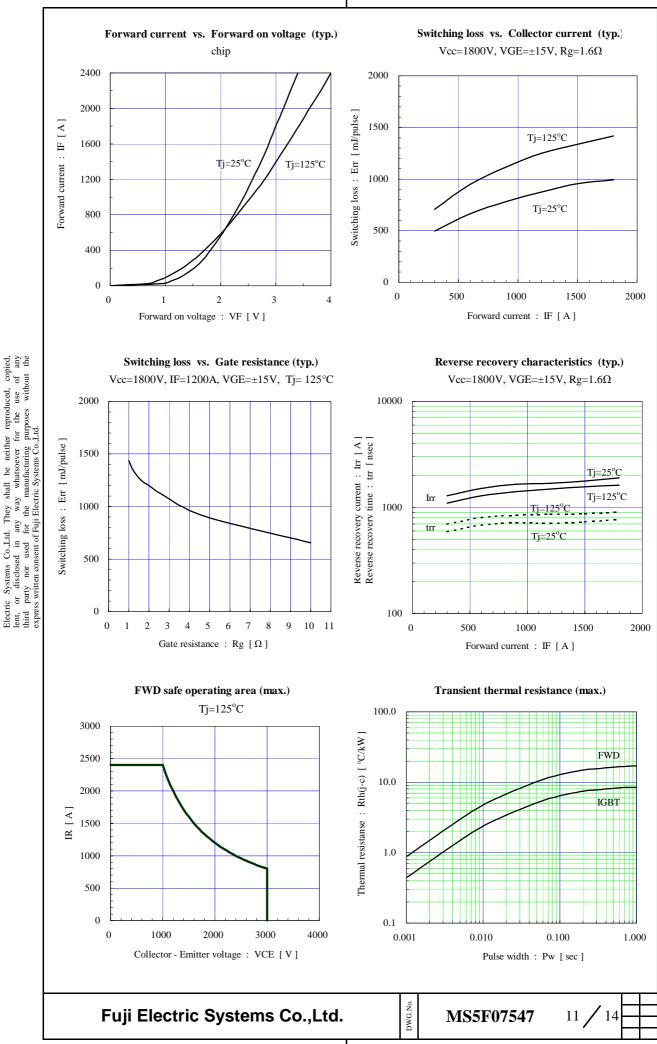
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Warnings

This product shall be used within its maximum rating (voltage, current, and temperature). This product
may be broken in case of using beyond the maximum ratings at measuring between sense emitter
and sense collector.

製品の最大定格(電圧,電流,温度等)の範囲内で御使用下さい。補助エミッタ端子と補助コレクタ端子間の測定で、 最大定格を超えて使用すると、素子が破壊する場合があります。

- Connect adequate fuse or protector of circuit between three-phase line and this product to prevent the
 equipment from causing secondary destruction, such as fire, its spreading, or explosion.

 万一の不慮の事故で素子が破壊した場合を考慮し、商用電源と本製品の間に適切な容量のヒューズ又はブレーカー
 を必ず付けて火災、爆発、延焼等の2次破壊を防いでください。
- Use this product after realizing enough working on environment and considering of product's reliability life.
 This product may be broken before target life of the system in case of using beyond the product's reliability life.

製品の使用環境を十分に把握し、製品の信頼性寿命が満足できるか検討の上、本製品を適用して下さい。製品の信頼性寿命を超えて使用した場合、装置の目標寿命より前に素子が破壊する場合があります。

- If the product had been used in the environment with acid, organic matter, and corrosive gas (hydrogen sulfide, sulfurous acid gas), the product's performance and appearance can not be ensured easily.
 酸・有機物・腐食性ガス(硫化水素, 亜硫酸ガス等)を含む環境下で使用された場合、製品機能・外観等の保証はできません。
- Use this product within the power cycle curve (Technical Rep.No.: MT5F12959). Power cycle capability is classified to delta-Tj mode which is stated as above and delta-Tc mode. Delta-Tc mode is due to rise and down of case temperature (Tc), and depends on cooling design of equipment which use this product. In application which has such frequent rise and down of Tc, well consideration of product life time is necessary. 本製品は、パワーサイクル寿命カーブ以下で使用下さい(技術資料No.: MT5F12959)。パワーサイクル耐量にはこのΔTj による場合の他に、ΔTcによる場合があります。これはケース温度(Tc)の上昇下降による熱ストレスであり、本製品をご使用する際の放熱設計に依存します。ケース温度の上昇下降が頻繁に起こる場合は、製品寿命に十分留意してご使用下さい。
- Never add mechanical stress to deform the main or control terminal. The deformed terminal may cause poor contact problem.
 主端子及び制御端子に応力を与えて変形させないで下さい。 端子の変形により、接触不良などを引き起こす場合があります。
- Use this product with keeping the cooling fin's flatness between screw holes within 50um at 100mm and
 the roughness within 10um. Also keep the tightening torque within the limits of this specification. Too large
 convex of cooling fin may cause isolation breakdown and this may lead to a critical accident. On the other
 hand, too large concave of cooling fin makes gap between this product and the fin bigger, then, thermal
 conductivity will be worse and over heat destruction may occur.

冷却フィンはネジ取り付け位置間で平坦度を100mmで50um以下、表面の粗さは10um以下にして下さい。過大な凸反りがあったりすると本製品が絶縁破壊を起こし、重大事故に発展する場合があります。また、過大な凹反りやゆがみ等があると、本製品と冷却フィンの間に空隙が生じて放熱が悪くなり、熱破壊に繋がることがあります。

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Warnings

In case of mounting this product on cooling fin, use thermal compound to secure thermal conductivity. If the
thermal compound amount was not enough or its applying method was not suitable, its spreading will not be
enough, then, thermal conductivity will be worse and thermal run away destruction may occur.
 Confirm spreading state of the thermal compound when its applying to this product.

(Spreading state of the thermal compound can be confirmed by removing this product after mounting.) 素子を冷却フィンに取り付ける際には、熱伝導を確保するためのコンパウンド等をご使用ください。又、塗布量が不足したり、塗布方法が不適だったりすると、コンパウンドが十分に素子全体に広がらず、放熱悪化による熱破壊に繋がる事があります。

コンパウンドを塗布する際には、製品全面にコンパウンドが広がっている事を確認して〈ださい。 (実装した後に素子を取りはずすとコンパウンドの広がり具合を確認する事が出来ます。)

- It shall be confirmed that IGBT's operating locus of the turn-off voltage and current are within the RBSOA specification. This product may be broken if the locus is out of the RBSOA.
 ターンオフ電圧・電流の動作軌跡がRBSOA仕様内にあることを確認して下さい。RBSOAの範囲を超えて使用すると素子が破壊する可能性があります。
- If excessive static electricity is applied to the control terminals, the devices may be broken. Implement some countermeasures against static electricity.
 制御端子に過大な静電気が印加された場合、素子が破壊する場合があります。取り扱い時は静電気対策を実施して下さい。
- Never add the excessive mechanical stress to the main or control terminals when the product is applied to
 equipments. The module structure may be broken.
 素子を装置に実装する際に、主端子や制御端子に過大な応力を与えないで下さい。端子構造が破壊する可能性があります。
- In case of insufficient -VGE, erroneous turn-on of IGBT may occur. -VGE shall be set enough value to prevent this malfunction. (Recommended value: -VGE = -15V) 逆パイアスゲート電圧-VGEが不足しますと誤点弧を起こす可能性があります。誤点弧を起こさない為に-VGEは十分な値で設定して下さい。(推奨値:-VGE = -15V)
- In case of higher turn-on dv/dt of IGBT, erroneous turn-on of opposite arm IGBT may occur. Use this product in the most suitable drive conditions, such as +VGE, -VGE, RG, CGE to prevent the malfunction. ターンオン dv/dt が高いと対向アームのIGBTが誤点弧を起こす可能性があります。誤点弧を起こさない為の最適なドライプ条件(+VGE, -VGE, RG, CGE)でご使用下さい。
- This product may be broken by avalanche in case of VCE beyond maximum rating VCES is applied between C-E terminals. Use this product within its maximum voltage.
 VCESを超えた電圧が印加された場合、アバランシェを起こして素子破壊する場合があります。VCEは必ず最大定格の範囲内でご使用下さい。

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